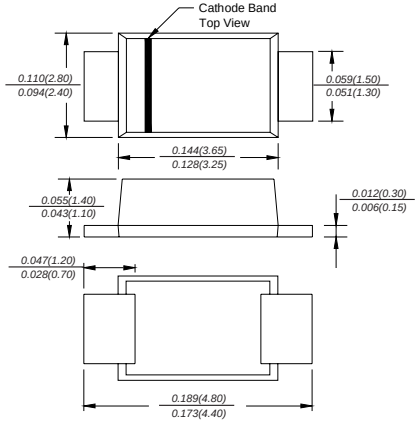
ES3AF THRU ES3JF

SURFACE MOUNT SUPER FAST RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Amperes

SMAF



Dimensions in inches and (millimeters)

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Super fast switching for high efficiency
- Low reverse leakage
- Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260℃/10 seconds at terminals
- Glass passivated chip junction

MECHANICAL DATA

Case: JEDEC SMAF molded plastic body over passivated chip
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight:0.0018 ounce, 0.064 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.
Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

MDD Catalog Number	*SYMBOLS*	ES3AF	ES3BF	ES3CF	ES3DF	ES3EF	ES3GF	ES3JF	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	VOLTS
Maximum average forward rectified current at T_L=55℃	$I_{(AV)}$	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50.0							Amps
Maximum instantaneous forward voltage at 3.0A	V_F	0.95				1.25		1.7	Volts
Maximum DC reverse current T_A=25℃ at rated DC blocking voltage T_A=125℃	I_R	5.0 200.0							μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	35							ns
Typical junction capacitance (NOTE 2)	C_J	60.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	40.0							°C/W
Operating junction and storage temperature range	T_J,T_{STG}	-50 to +150							°C

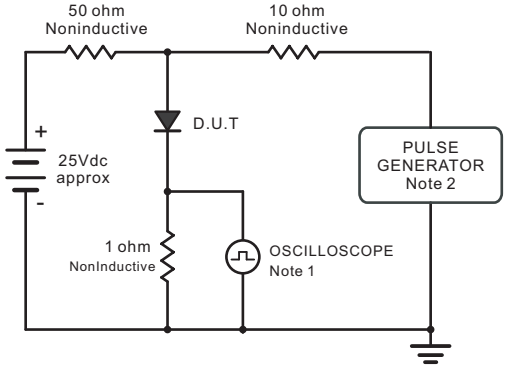
Note:1.Reverse recovery condition I_F=0.5A,I_R=1.0A,Irr=0.25A
2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.
3.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

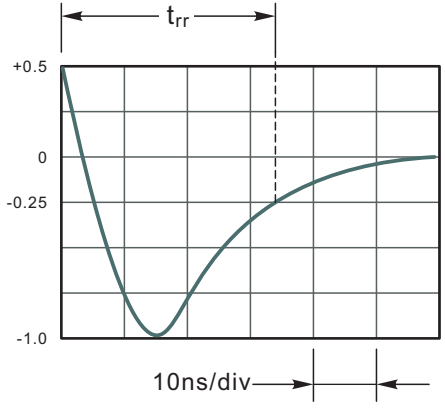
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RATINGS AND CHARACTERISTIC CURVES ES3AF THRU ES3JF

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram





Set time Base for 10ns/div

Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm,22pF.
2. Ries Time =10ns, max.
Source Impedance = 50 ohms.

Fig.2 Maximum Average Forward Current Rating

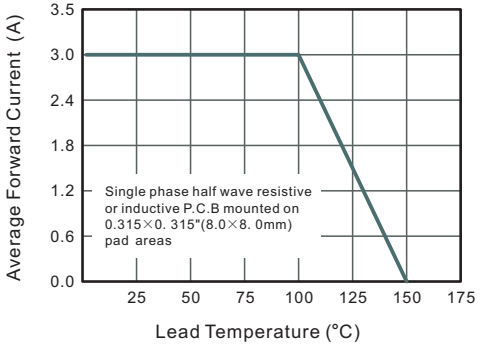


Fig.3 Typical Reverse Characteristics

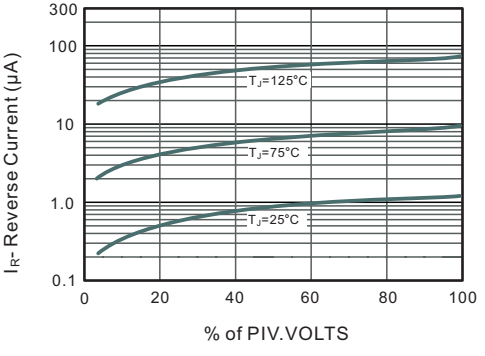


Fig.4 Typical Forward Characteristics

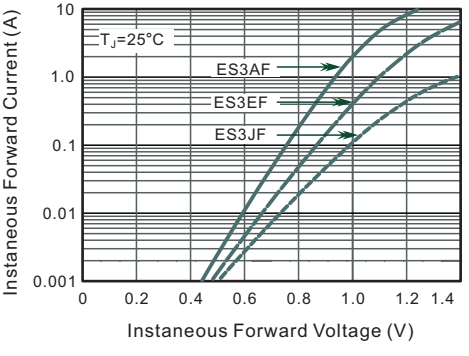
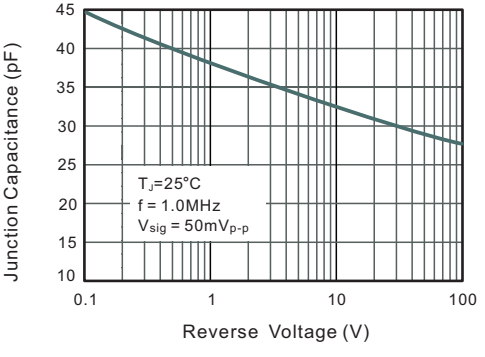


Fig.5 Typical Junction Capacitance



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